

Excellent Integrated System Limited

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Vishay Semiconductor/Diodes Division VB40100C-M3/8W

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Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite

Datasheet of VB40100C-M3/8W - DIODE SCHOTTKY 40A 100V TO-263AB

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com





TMBS[®]

TO-263AB

VB40100C

TO-263AB

2 x 20 A

100 V

250 A

0.61 V

150 °C

Common cathode

►

PIN 1 O-

PRIMARY CHARACTERISTICS

Package

I_{F(AV)} V_{BBM}

I_{FSM}

 V_F at $I_F = 20$ A

T_J max.

Diode variation

VB40100C-M3

Vishay General Semiconductor

Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.38$ V at $I_F = 5$ A

FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Low thermal resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters, and reverse battery protection.

MECHANICAL DATA

Case: TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER		SYMBOL	VB40100C	UNIT	
Maximum repetitive peak reverse voltage		V _{RRM}	100	V	
Maximum average forward rectified current (fig. 1)	per device	I _{F(AV)}	40	А	
	per diode		20		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	250	A	
Voltage rate of change (rated VR)		dV/dt	10 000	V/µs	
Operating junction and storage temperature range		T _J , T _{STG}	- 40 to + 150	°C	

COMPLIANT HALOGEN

Revision: 15-May-13

Document Number: 87987

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VB40100C-M3

Vishay General Semiconductor

ELECTRICAL CHARACTERISTICS ($T_A = 25$ °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I _F = 5 A	T _A = 25 °C	VF	0.47	-	V	
	I _F = 10 A			0.54	-		
	I _F = 20 A			0.67	0.73		
	I _F = 5 A	T _A = 125 °C		0.38	-		
	I _F = 10 A			0.45	-		
	I _F = 20 A			0.61	0.67		
Reverse current at rated V _R per diode ⁽²⁾	V _R = 70 V	T _A = 25 °C	I _R	9	-	μA	
		T _A = 125 °C		10	-	mA	
	$V_{\rm P} = 100 \text{ V}$	T _A = 25 °C		-	1000	μA	
		T _A = 125 °C		21	45	mA	

Notes

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width £ 40 ms

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER	SYMBOL	VB40100C	UNIT		
Typical thermal resistance per diode	$R_{\theta JC}$	2.0	°C/W		

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-263AB	VB40100C-M3/4W	1.39	4W	50/tube	Tube	
TO-263AB	VB40100C-M3/8W	1.39	8W	800/reel	Tape and reel	

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

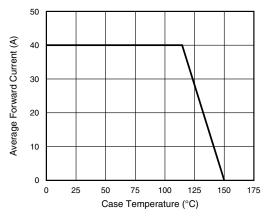


Fig. 1 - Forward Current Derating Curve

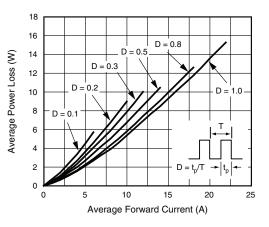


Fig. 2 - Forward Power Loss Characteristics Per Diode

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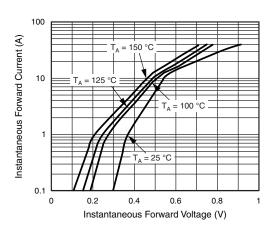


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

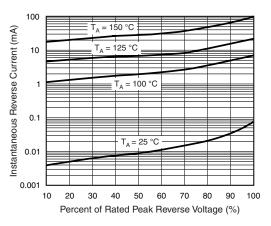
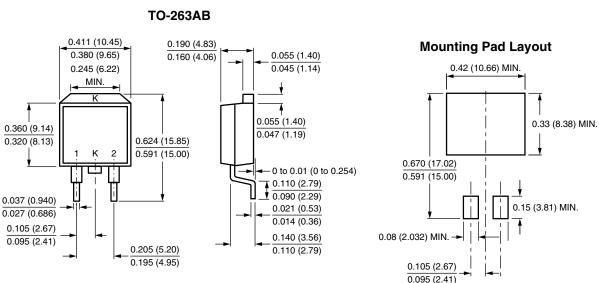


Fig. 4 - Typical Reverse Characteristics Per Diode





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VB40100C-M3

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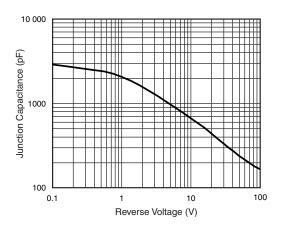


Fig. 5 - Typical Junction Capacitance Per Diode

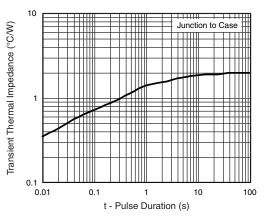


Fig. 6 - Typical Transient Thermal Impedance Per Diode

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